VS-50WQ04FNHM3

Vishay Semiconductors

Schottky Rectifier, 5.5 A



- · Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- Small foot print, surface mountable
- High frequency operation
- Popular D-PAK outline
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-50WQ04FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

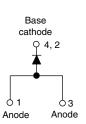
MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	5.5	A				
V _{RRM}		40	V				
I _{FSM}	t _p = 5 μs sine	340	A				
V _F	5 A _{pk} , T _J = 125 °C	0.44	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-50WQ04FNHM3	UNITS				
Maximum DC reverse voltage	V _R	40	N/				
Maximum working peak reverse voltage	V _{RWM}	40	V				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	BOL TEST CONDITIONS		VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 135 °C, rectangular waveform		5.5			
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	550	А		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	90			
Non-repetitive avalanche energy E _{AS}		T _J = 25 °C, I _{AS} = 1.5 A, L = 8 mH		9	mJ		
Repetitive avalanche current I _{AR}		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.2	А		



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Revision: 21-Aug-13

PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	5.5 A					
V _R	40 V					
V _F at I _F	See Electrical table					
I _{RM}	40 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Single die					
E _{AS}	9 mJ					



HALOGEN

FREE

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ELECTRICAL SPECIFICATIONS	EL	ECT	RICAL	SPEC	IFICAT	ONS
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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS VALUES UI			UNITS		
		5 A	T.I = 25 °C	0.51	V		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	1j=25 0	0.63			
See fig. 1	¥FM \''	5 A	T.I = 125 °C	0.44			
		10 A	1j = 125 C	0.59			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA		
See fig. 2	IRM \''	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	40			
Thereshold voltage	V _{F(TO)}			0.27	V		
Forward slope resistance	r _t	- T _J =T _J maximum		26.77	mΩ		
Typical junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 405		pF			
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0 nH			nH		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T_{J} ⁽¹⁾ , T_{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W		
Approvimete weight			0.3	g		
Approximate weight			0.01	oz.		
Marking device		Case style D-PAK	50WQ0	4FNH		

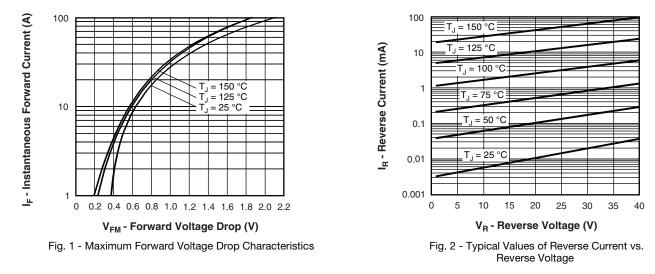
Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

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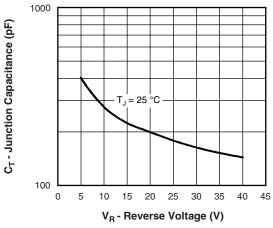


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

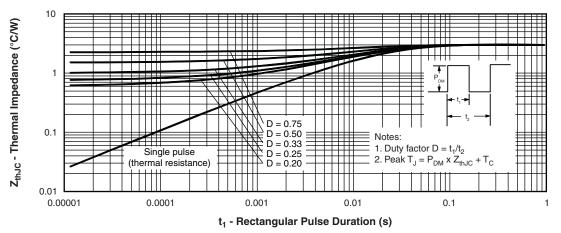


Fig. 4 - Maximum Thermal Impedance $\mathsf{Z}_{\mathsf{thJC}}$ Characteristics

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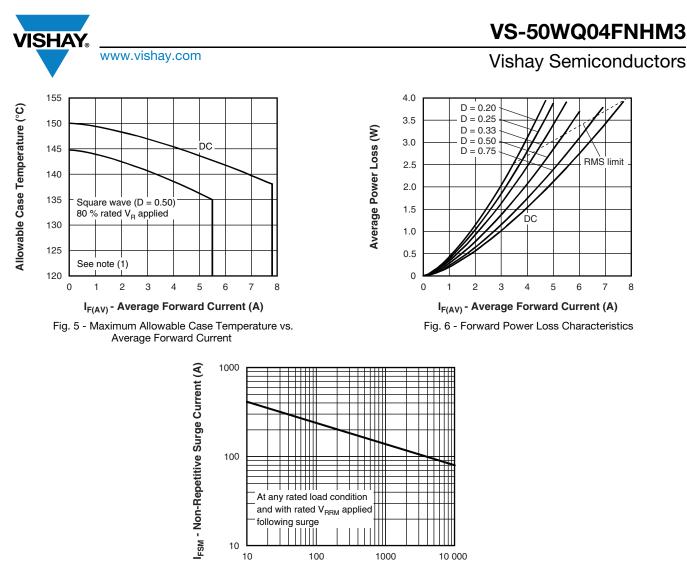
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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

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ORDERING INFORMATION TABLE

Device code	VS-	50	w	Q	04	FN	TRL	н	М3
	1	2	3	4	5	6	7	8	9
	1	- Vis	hay Sen	nicondu	ctors pro	oduct			
	2		rent rati		-				
			ckage id		,				
			= D-PAK						
	4	- Scł	nottky "G)" series	;				
	5	- Vol	tage rati	ng (04 =	= 40 V)				
			= TO-2						
		- • None = Tube							
	• TR = Tape and reel								
		• TRL = Tape and reel (left oriented)							
		• TI	RR = Ta	pe and	reel (rig	ht orien	ted)		
	8	- H=	AEC-Q	101 qua	alified				
	9	- Env	vironmer	ntal digit	:				
		M3		on froo	DALC	complic	nt and	tormino	tiona loa

M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-50WQ04FNHM3	75	3000	Antistatic plastic tube				
VS-50WQ04FNTRHM3	2000	2000	13" diameter reel				
VS-50WQ04FNTRRHM3	3000	3000	13" diameter reel				
VS-50WQ04FNTRLHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

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